NSN 5962-01-342-2194

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-342-2194 **Body Length:** 1.060 inches **Body Width:** Between 0.220 inches and 0.310 inches **Body Height:** Between 0.130 inches and 0.185 inches **Maximum Power Dissipation Rating:** 2.0 watts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Hermetically sealed and burn in and monolithic and programmable and w/clock **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Input Circuit Pattern:** 14 input **Case Outline Source And Designator:** D-8 mil-m-38510 **Current Rating Per Characteristic:** 185.00 milliamperes reverse current, dc absolute **Terminal Surface Treatment:** Solder **Product Name:** Registered and-or gate array Voltage Rating And Type Per Characteristic: -0.5 volts power source and 7.0 volts power source **Time Rating Per Chacteristic:** 45.00 nanoseconds propagation delay time, high to low level output and 45.00 nanoseconds propagation delay time, low to high level output Memory Device Type: Pal **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 20 printed circuit Shelf Life: N/a Unit Of Measure:

NSN 5962-01-342-2194

Memory Microcircuit - Page 2 of 2

Demilitarization:

Yes - demil/mli

Fiig:

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